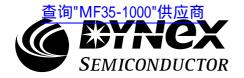


1200V

40A

400A

10μC 0.2ns



Fast Recovery Diode

 V_{RRM}

I_{F(AV)}

Replaces March 1998 version, DS4625-3.1

DSDS4625-4.0 January 2000

KEY PARAMETERS

APPLICATIONS

- Inverse, Parallel Or Series Connected Diode
- Power Supplies
- High Frequency Applications

FEATURES

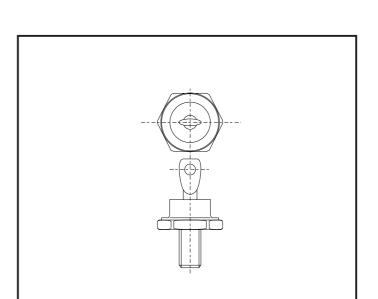
- Glass Passivation
- High Voltage Capability
- Fast Recovery Characteristics

VOLTAGE RATINGS

Type Number	Repetitive Peak Reverse Voltage V	Conditions
MF35 - 1200 MF35 - 1000 MF35 - 800 MF35 - 600	1200 1000 800 600	$V_{RSM} = V_{RRM} + 100V$

Lower voltage grades available.

For stud anode add suffix 'R' to type number. e.g. MF35-1200R.



Outline type code: DO5. See Package Details for further information.

CURRENT RATINGS

Symbol	Parameter	Conditions	Max.	Units
I _{F(AV)}	Mean forward current	Half sine wave resistive load, T _{case} = 65°C	40	А
I _{F(RMS)}	RMS value	$T_{case} = 65^{\circ}C$	63	А
I _F	Continuous (direct) forward current	$T_{case} = 65^{\circ}C$	50	А

MF35

查询"MF35-1000"供应商 SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) forward current	10ms half sine; with $V_{RRM} \le 10V$, $T_j = 125^{\circ}C$	400	А
l²t	I ² t for fusing	10ms half sine; T _j = 125°C	800	A ² s

THERMAL AND MECHANICAL DATA

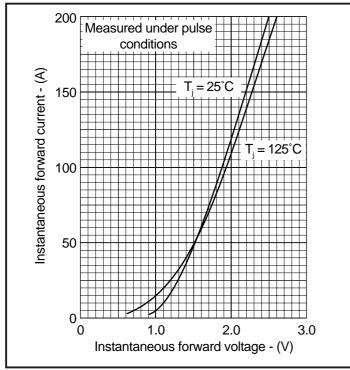
Symbol	Parameter	Conditions	Min.	Max.	Units
R _{th(j-c)}	Thermal resistance - junction to case	dc	-	0.8	°C/W
R _{th(c-h)}	Thermal resistance - case to heatsink	Mounting torque 3.5Nm with mounting compound	-	0.2	°C/W
T _{vj}	Virtual junction temperature	Forward (conducting)	-	125	°C
		Reverse (blocking)	-	125	°C
T _{stg}	Storage temperature range		-55	125	°C
-	Mounting torque		3.2	3.8	Nm

CHARACTERISTICS

Symbol	Parameter	Conditions	Тур.	Max.	Units
V _{FM}	Forward voltage	At 120A peak, T _{case} = 25°C	-	2.0	V
I _{RM}	Peak reverse current	At V _{RRM} , T _{case} = 100°C	-	5	mA
t _{rr}	Reverse recovery time	$I_F = 1A$, $di_{RR}/dt = 25A/\mu s$, $T_{case} = 25$ °C, $V_R = 100V$	-	200	ns
Q_R	Recovered charge	$I_F = 50A$, $di_{RR}/dt = 50A/\mu s$, $T_{case} = 25$ °C, $V_R = 100V$	-	10	μС
V _{TO}	Threshold voltage	At $T_{v_j} = 125^{\circ}C$	-	1.2	V
r _T	Slope resistance	At $T_{v_j} = 125^{\circ}C$	-	7.0	mΩ

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CURVES



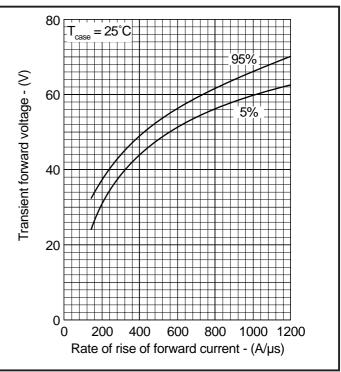
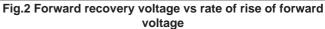
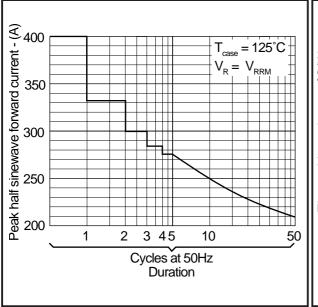


Fig.1 Maximum (limit) forward characteristics





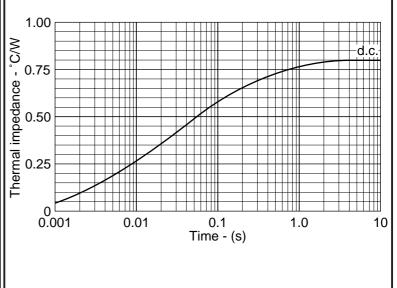


Fig.3 Surge (non-repetitive) forward current vs time

Fig.4 Maximum transient thermal impedance

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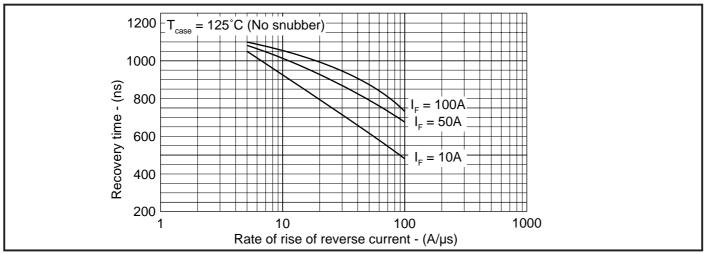


Fig.5 Recovery time vs dl_R/dt

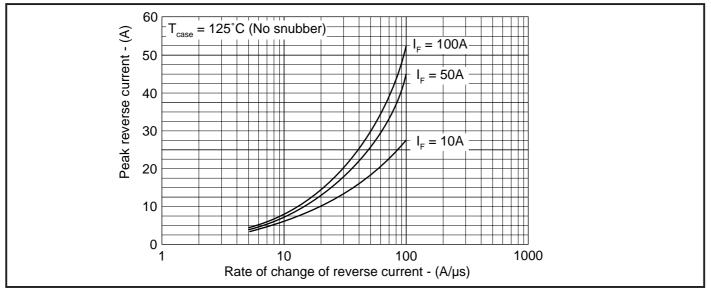


Fig.6 Peak reverse current vs dl_R/dt

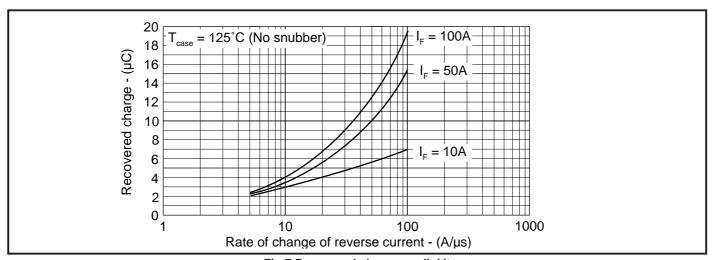


Fig.7 Recovered charge vs dI_R/dt

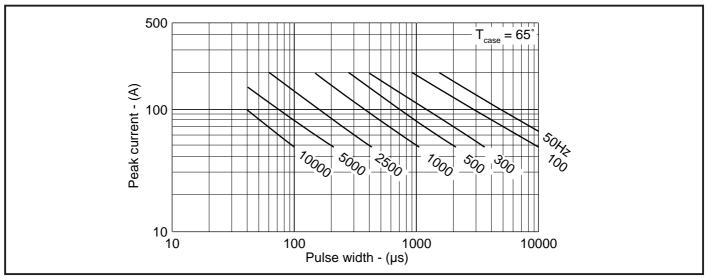


Fig.8 Frequency curves - square waveform

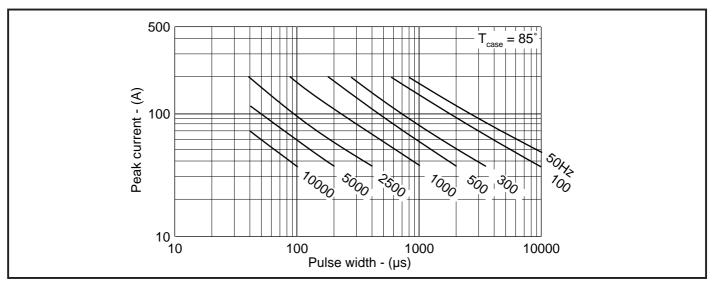


Fig.9 Frequency curves - square waveform

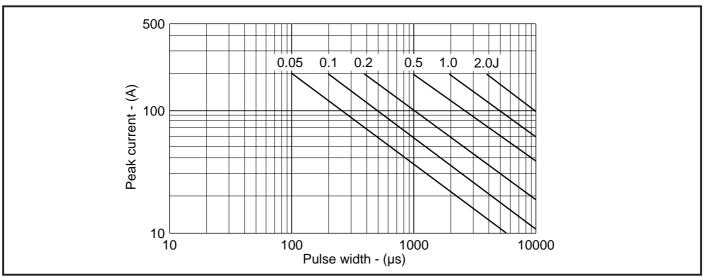


Fig.10 Energy per pulse - square waveform

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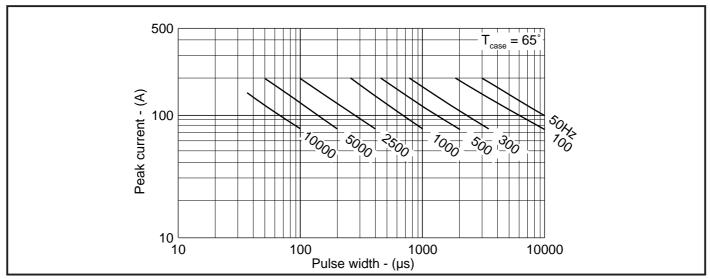


Fig.11 Frequency curves - sine waveform

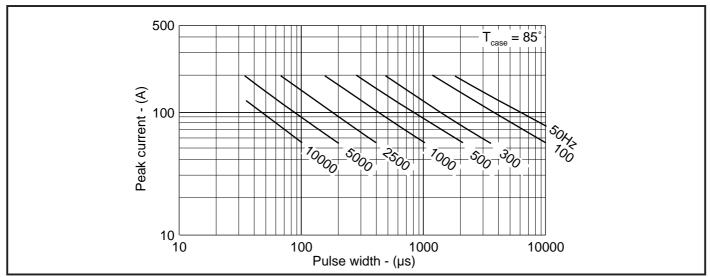


Fig.12 Frequency curves - sine waveform

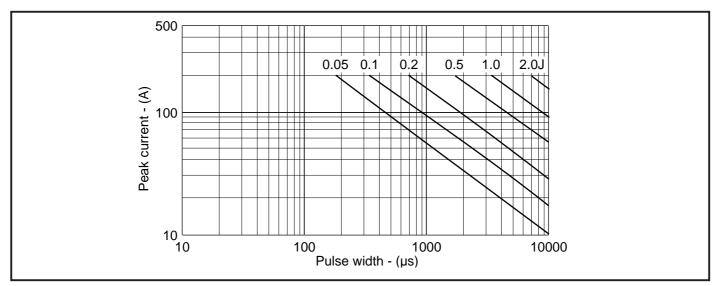
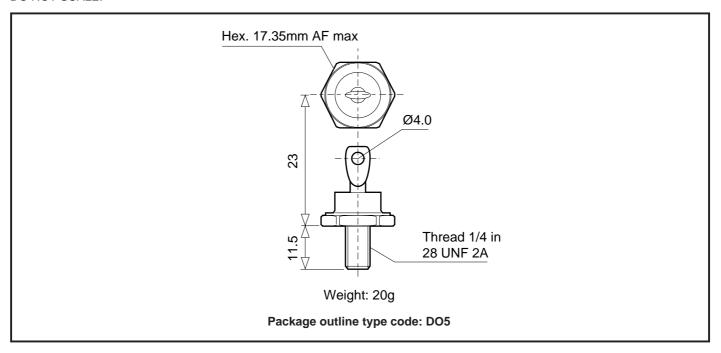


Fig.13 Energy per pulse - sine waveform

查询"MF35-1000"供应商 PACKAGE DETAILS

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



ASSOCIATED PUBLICATIONS

Title	Application Note	
	Number	
Calculating the junction temperature or power semiconductors	AN4506	
Thyristor and diode measurement with a multi-meter	AN4853	
Use of V_{TO} , r_{T} on-state characteristic	AN5001	

MF35

查询"MF35-1000"供应商

POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink / clamping systems in line with advances in device types and the voltage and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group continues to offer high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the up to date CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete solution (PACs).

HEATSINKS

Power Assembly has it's own proprietary range of extruded aluminium heatsinks. They have been designed to optimise the performance or our semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest Sales Representative or the factory.



http://www.dynexsemi.com

e-mail: power_solutions@dynexsemi.com

HEADQUARTERS OPERATIONS DYNEX SEMICONDUCTOR LTD

Doddington Road, Lincoln. Lincolnshire. LN6 3LF. United Kingdom. Tel: 00-44-(0)1522-500500 Fax: 00-44-(0)1522-500550

DYNEX POWER INC.

Unit 7 - 58 Antares Drive, Nepean, Ontario, Canada K2E 7W6. Tel: 613.723.7035 Fax: 613.723.1518 Toll Free: 1.888.33.DYNEX (39639) CUSTOMER SERVICE CENTRES

France, Benelux, Italy and Spain Tel: +33 (0)1 69 18 90 00. Fax: +33 (0)1 64 46 54 50 North America Tel: 011-800-5554-5554. Fax: 011-800-5444-5444 UK, Germany, Scandinavia & Rest Of World Tel: +44 (0)1522 500500. Fax: +44 (0)1522 500020

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Preliminary Information: The product is in design and development. The datasheet represents the product as it is understood but details may change.

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